

ON Semiconductor®

# **NC7S00**

# TinyLogic® HS 2-Input NAND Gate

## **General Description**

The NC7S00 is a single 2-Input high performance CMOS NAND Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad  $V_{CC}$  range. ESD protection diodes inherently guard both inputs and output with respect to the  $V_{CC}$  and GND rails. Three stages of gain between inputs and output assures high noise immunity and reduced sensitivity to input edge rate.

### **Features**

- Space saving SOT23 or SC70 5-lead package
- Ultra small MicroPak™ leadless package
- High speed: t<sub>PD</sub> 3.5 ns typ
- $\blacksquare$  Low Quiescent Power:  $I_{CC} < 1~\mu\text{A}$
- $\blacksquare$  Balanced Output Drive: 2 mA I $_{\rm OL}$ , -2 mA I $_{\rm OH}$
- Broad V<sub>CC</sub> Operating Range: 2V–6V
- Balanced Propagation Delays
- Specified for 3V operation

## **Ordering Code:**

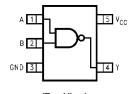
ſ	Order Number	Package Product Code		Package Description	Supplied As	
	Order Number	Number	Top Mark	Fackage Description	Supplied As	
	NC7S00M5X	MA05B	7S00	5-Lead SOT23, JEDEC MO-178, 1.6mm	3k Units on Tape and Reel	
	NC7S00P5X	MAA05A	S00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel	
	NC7S00L6X	MAC06A	A3	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel	

# **Logic Symbol**



# **Connection Diagrams**

# Pin Assignments for SC70 and SOT23



(Top View)

# Pad Assignments for MicroPak

Α	1		6	VCC
В	2		5	NC
GND	3		4	Υ

### (Top Thru View)

# **Pin Descriptions**

Pin Names	Description
A, B	Input
Y	Output
NC	No Connect

### **Function Table**

 $Y = \overline{AB}$ 

Inp	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level

 $\mathsf{L} = \mathsf{LOW} \; \mathsf{Logic} \; \mathsf{Level}$ 

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Publication Order Number: NC7S00/D

# $\begin{array}{lll} \textbf{Absolute Maximum Ratings} (\text{Note 1}) & \textbf{Recommended Operating} \\ \text{Supply Voltage (V_{CC})} & -0.5 \text{V to } +7.0 \text{V} \end{array}$

DC Input Diode Current (I <sub>IK</sub> )		Supply Voltage (V <sub>CC</sub> )	2.0V-6.0V
$@V_{IN} \le -0.5V$	–20 mA	Input Voltage (V <sub>IN</sub> )	0V-V <sub>CC</sub>
$@V_{IN} \ge V_{CC} + 0.5V$	+20 mA	Output Voltage (V <sub>OUT</sub> )	0V-V <sub>CC</sub>
DC Input Voltage (V <sub>IN</sub> )	$-0.5V$ to $V_{CC} + 0.5V$	Operating Temperature (T <sub>A</sub> )	-40°C to +85°C
DC Output Diode Current (I <sub>OK</sub> )		Input Rise and Fall Time $(t_r, t_f)$	
$@V_{OUT} < -0.5V$	–20 mA	V <sub>CC</sub> @ 2.0V	0-1000 ns
$@V_{OUT} > V_{CC} + 0.5V$	+20 mA	V <sub>CC</sub> @ 3.0V	0-750 ns
DC Output Voltage (V <sub>OUT</sub> )	$-0.5V$ to $V_{CC}$ + $0.5V$	V <sub>CC</sub> @ 4.5V	0–500 ns
DC Output Source		V <sub>CC</sub> @ 6.0V	0-400 ns
or Sink Current (I <sub>OUT</sub> )	±12.5 mA	Thermal Resistance ( $\theta_{JA}$ )	
DC V <sub>CC</sub> or Ground Current		SOT23-5	300°C/W
per Output Pin (I <sub>CC</sub> or I <sub>GND</sub> )	±25 mA	SC70-5	425°C/W

260°C

per Output Pin ( $I_{CC}$  or  $I_{GND}$ )  $\pm 25$  mA SC70-5 Storage Temperature ( $T_{STG}$ )  $-65^{\circ}$ C to  $+150^{\circ}$ C

Junction Temperature ( $T_J$ ) 150°C Lead Temperature ( $T_L$ );

(Soldering, 10 seconds)

Power Dissipation (P<sub>D</sub>) @ +85°C

SOT23-5 200 mW SC70-5 150 mW

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. ON Semiconductor does not recommend operation of circuits outside the databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

### **DC Electrical Characteristics**

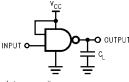
Symbol	Parameter	v <sub>cc</sub>		T <sub>A</sub> = +25°C	;	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	Conditions
Symbol		(V)	Min	Тур	Max	Min	Max	Units	Conditions
V <sub>IH</sub>	HIGH Level Input Voltage	2.0	1.50			1.50		V	
		3.0 - 6.0	0.7 V <sub>CC</sub>			0.7V <sub>CC</sub>		V	
V <sub>IL</sub>	LOW Level Input Voltage	2.0			0.50		0.50	V	
		3.0 - 6.0			$0.3V_{CC}$		$0.3\mathrm{V}_{\mathrm{CC}}$	V	
V <sub>OH</sub>	HIGH Level Output Voltage	2.0	1.90	2.0		1.90			
		3.0	2.90	3.0		2.90		٧	$I_{OH} = -20 \mu A$ $V_{IN} = V_{IL}$
		4.5	4.40	4.5		4.40			$V_{IN} = V_{IL}$
		6.0	5.90	6.0		5.90			
									V <sub>IN</sub> = V <sub>IL</sub>
		3.0	2.68	2.85		2.63		V	$I_{OH} = -1.3 \text{ mA}$
		4.5	4.18	4.35		4.13		٧	$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.85		5.63			$I_{OH} = -2.6 \text{ mA}$
V <sub>OL</sub>	LOW Level Output Voltage	2.0		0.0	0.10		0.10		
		3.0		0.0	0.10		0.10	V	$I_{OL} = 20 \mu A$ $V_{IN} = V_{IH}$
		4.5		0.0	0.10		0.10	v	$V_{IN} = V_{IH}$
		6.0		0.0	0.10		0.10		
									$V_{IN} = V_{IH}$
		3.0		0.1	0.26		0.33	V	$I_{OL} = 1.3 \text{ mA}$
		4.5		0.1	0.26		0.33	٧	$I_{OL} = 2 \text{ mA}$
		6.0		0.1	0.26		0.33		I <sub>OL</sub> = 2.6 mA
I <sub>IN</sub>	Input Leakage Current	6.0			±0.1		±1.0	μΑ	$V_{IN} = V_{CC}$ , GND
I <sub>CC</sub>	Quiescent Supply Current	6.0			1.0		10.0	μΑ	$V_{IN} = V_{CC}$ , GND

# **AC Electrical Characteristics**

Symbol	ol Parameter	v <sub>cc</sub>		$T_A = +25^{\circ}C$		T <sub>A</sub> = -40°	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Conditions	Figure
Cymbol		(V)	Min	Тур	Max	Min	Max	Units	Conditions	Number
t <sub>PLH</sub> ,	Propagation Delay	5.0		3.5	15			ns	$C_{L} = 15 \text{ pF}$	
t <sub>PHL</sub>		2.0		19	100		125			Figures 1, 3
		3.0		10.5	27		35		0 50 - 5	
		4.5		7.5	20		25	ns $C_L = 50 \text{ pF}$		., 0
		6.0		6.5	17		21			
t <sub>TLH</sub> ,	Output Transition Time	5.0		3.0	10			ns	C <sub>L</sub> = 15 pF	
$t_{THL}$		2.0		25	125		155			l
		3.0		16	35		45	ns	0 50 5	Figures 1, 3
		4.5		11	25		31	115	$C_L = 50 pF$	
		6.0		9	21		26			
C <sub>IN</sub>	Input Capacitance	Open		2	10		10	pF		
C <sub>PD</sub>	Power Dissipation Capacitance	5.0		6				pF	(Note 3)	Figure 2

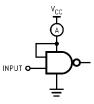
Note 3:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption ( $I_{CCD}$ ) at no output loading and operating at 50% duty cycle. (See Figure 2.)  $C_{PD}$  is related to  $I_{CCD}$  dynamic operating current by the expression:  $I_{CCD} = (C_{PD}) (V_{CC}) (f_{|N}) + (I_{CC} static)$ .

# **AC Loading and Waveforms**



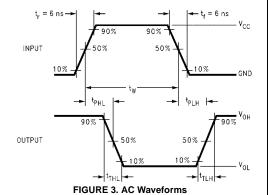
 ${
m C_L}$  includes load and stray capacitance Input PRR = 1.0 MHz,  ${
m t_W}$  = 500 ns

FIGURE 1. AC Test Circuit

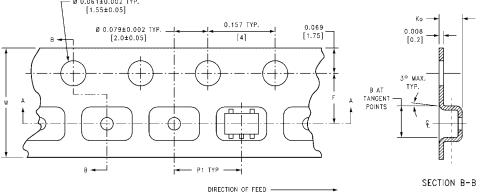


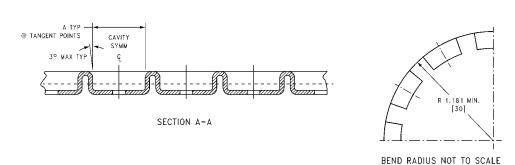
Input = AC Waveform; PRR = variable; Duty Cycle = 50%

FIGURE 2. I<sub>CCD</sub> Test Circuit

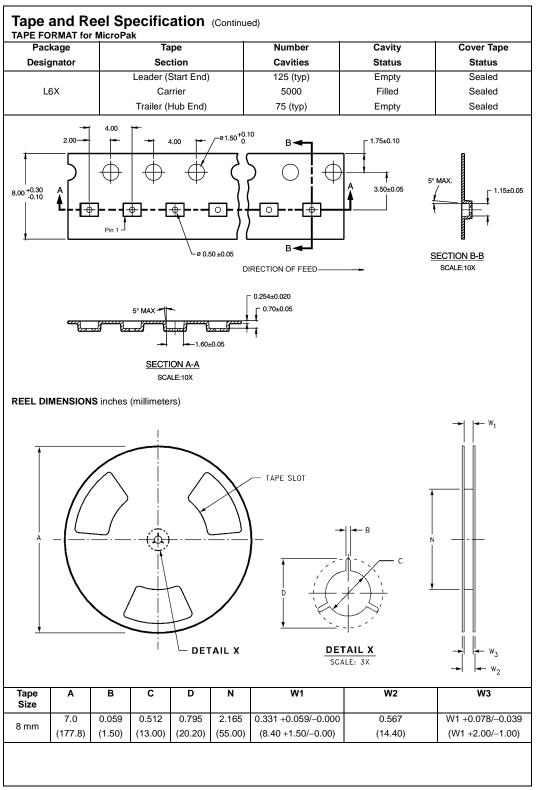


#### **Tape and Reel Specification** TAPE FORMAT for SC70 and SOT23 Package Number Cavity Cover Tape Section Cavities Designator Status Status Leader (Start End) 125 (typ) Empty Sealed M5X, P5X 3000 Filled Carrier Sealed Trailer (Hub End) Sealed 75 (typ) Empty TAPE DIMENSIONS inches (millimeters) Ø 0.061±0.002 TYP. [1.55±0.05] Ø 0.079±0.002 TYP. [2.0±0.05] [4]

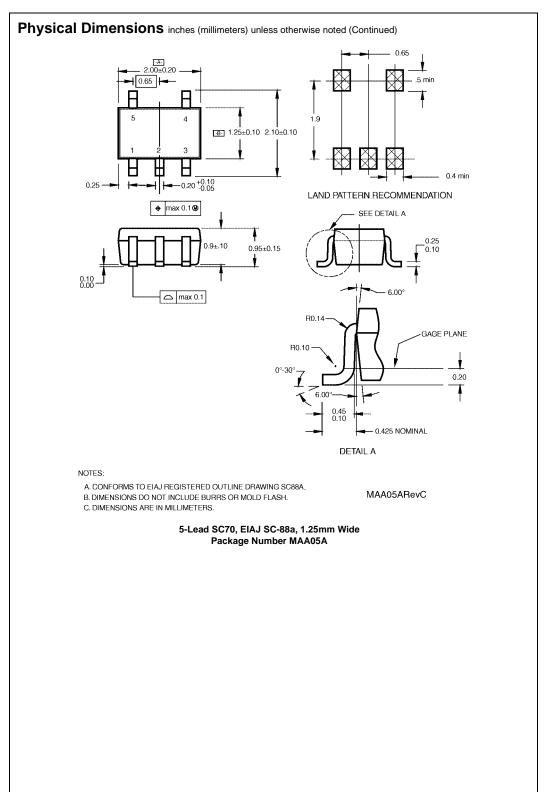




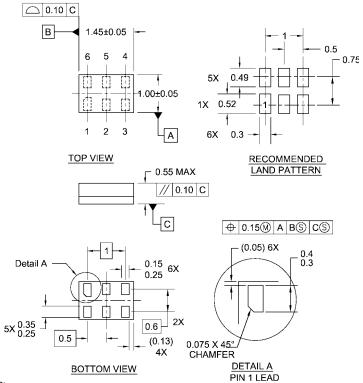
Package	Tape Size	DIM A DIM B		DIM F	DIM K <sub>o</sub>	DIM P1	DIM W	
SC70-5	8 mm	0.093	0.096	0.138 ±0.004	0.053 ±0.004	0.157	0.315 ±0.004	
		(2.35)	(2.45)	(3.5 ±0.10)	(1.35 ±0.10)	(4)	(8 ±0.1)	
SOT23-5	8 mm	0.130	0.130	0.138 ±0.002	0.055 ±0.004	0.157	0.315 ±0.012	
50123-5		(3.3)	(3.3)	(3.5 ±0.05)	(1.4 ±0.11)	(4)	(8 ±0.3)	



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# Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



### Notes:

- 1. JEDEC PACKAGE REGISTRATION IS ANTICIPATED 2. DIMENSIONS ARE IN MILLIMETERS 3. DRAWING CONFORMS TO ASME Y14.5M-1994

MAC06ARevB

6-Lead MicroPak, 1.0mm Wide Package Number MAC06A

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